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| 1. Record Nr. | UNINA990001207370403321 |
| Titolo | MULTIPLE criteria decision making : XII International Meeting of TIMS held in Kyoto, Japan, July 24-26, 1975 |
| Pubbl/distr/stampa | Berlin [etc.] : Springer-Verlag, 1976 |
| Collana | Lecture notes in economics and mathematical systems ; 123 |
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| 2. Record Nr. | UNISA996280192803316 |
| Titolo | AIEE standard for semiconductor rectifier components |
| Pubbl/distr/stampa | New York : , : IEEE, , 1962 |
| ISBN | 1-5044-0393-2 |
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| Disciplina | 621.3815322 |
| Soggetti | Semiconductor rectifiers - Standards
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Electric current rectifiers |
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| Sommario/riassunto | Definitions given herein apply specifically to semiconductor components used for rectification or control of electric power, or both. For the purpose of this standard, a semiconductor rectifier component is a semiconductor rectifier cell, rectifier diode, or rectifier stack. Note that the name of the actual semiconductor material (selenium, silicon, |

etc.) may be substituted in place of the word "semiconductor" in the name of the components. Only those definitions likely to be needed by the user are included.
